Surface Mount General Purpose Rectifier





Features

- Low profile package
- Ideal for automated placement
- Glass passivated chip junction
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

Typical Applications

For use in general purpose rectification of power supplies, inverters, converters, and freewheeling diodes for consumer, and telecommunication.

Mechanical Data

• Package: DO-214AB (SMC)

Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant, halogen-free

- Terminals: Tin plated leads, solderable per
- J-STD-002 and JESD22-B102
- Polarity: Color band denotes the cathode end

■Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	GS8A	GS8B	GS8D	GS8G	GS8J	GS8K	GS8M
Device marking code			GS8A	GS8B	GS8D	GS8G	GS8J	GS8K	GS8M
Maximum Repetitive peak reverse voltage	V _{RRM}	V	50	100	200	400	600	800	1000
Maximum RMS Voltage	V _{RMS}	V	35	70	140	280	420	560	700
Maximum DC Blocking Voltage	V _{DC}	V	50	100	200	400	600	800	1000
Average Rectified Output Current @60Hz sine wave, Resistance load, TL (FIG.1)	Ι _ο	А	8.0						
Forward Surge Current (Non-repetitive) @60Hz Half-sine wave,1 cycle, Tj=25°C		٨	200						
Forward Surge Current (Non-repetitive) @1ms, square wave, 1 cycle, Tj=25°C	I _{FSM}	A				400			
Current squared time @1ms≤t8.3≤ms Tj=25℃,Rating of per diode	l²t	A ² s	166						
Typical junction capacitance @Measured at 1MHz and Applied Reverse Voltage of 4.0 V.D.C	Cj	pF	55						
Storage Temperature	T _{stg}	°C	-55 ~ +150						
Junction Temperature	Tj	°C	-55 ~ +150						

Electrical Characteristics ($T_a=25^{\circ}C$ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	GS8A	GS8B	GS8D	GS8G	GS8J	GS8K	GS8M
Maximum instantaneous forward voltage drop per diode	VF	V	IFM=8.0A	1.1						
Maximum DC reverse current at rated DC blocking voltage per	IR		Tj =25℃				5			
diode	чК	μA	Tj =125℃				100			

Thermal Characteristics $(T_a=25^{\circ}C \text{ Unless otherwise specified})$

PARAMETER	SYMBOL	UNIT	GS8A	GS8B	GS8D	GS8G	GS8J	GS8K	GS8M
	RθJ-A(1)					50			
Typical Thermal resistance	RθJ-L(1)	°C/W				18			
	RθJ-C(1)					15			

Note(1)

Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.6" x 0.6" (16 mm x 16 mm) copper pad areas

■Ordering Information (Example)

PREFERED P/N	PACKAGE CODE	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
GS8A~GS8M	F1	Approximate 0.261	3000	6000	42000	13" reel

Characteristics(Typical)



200 160 8.3ms Single Half Sine Wav JEDEC Method 120 80 40 0 2 4 6 8 10 20 40 60 80 100 1 Number of Cycles

FIG.2: Forward Surge Current Capability



100







Outline Dimensions



DC	DO-214AB (SMC)					
Dim	Min	Max				
А	6.60	7.11				
В	2.85	3.27				
С	5.59	6.22				
D	7.75	8.13				
E	1.99	2.61				
F	0.15	0.31				
G	0.76	1.52				
Н	0.10	0.20				

Suggested pad layout



Dim	Тур
Dim	Тур
P1	9.9
P2	3.84
Q1	3.03
Q2	3.82





GS8A THRU GS8M

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